NSN 5962-01-268-2908

Memory Microcircuit - Page 1 of 1



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Body Length:

Between 1.435 inches and 1.485 inches

Body Width:

Between 0.515 inches and 0.600 inches

Body Height:

Between 0.140 inches and 0.185 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Programmable and ultraviolet erasable and high speed and w/enable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

N-type metal oxide-semiconductor logic

Input Circuit Pattern:

17 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.6 volts power source and 22.0 volts power source

Time Rating Per Chacteristic:

200.00 nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Eprom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0